NSN 5961-01-408-6795

Semiconductor Device Set - Page 1 of 1



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End Application:
6625-01-363-6212
Internal Configuration:
Field effect all transistor
Channel Polarity And Control Type (non-core):
N-channel junction type all transistor
Component Name And Quantity:
2 transistor
Field Force Effect Type:
Electrostatic charge
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0